



#### REVISION HISTORY

<u>Revision</u>	<u>Description</u>	<u>Issue Date</u>
Rev. 1.0	Initial Issue	Jul.25.2004
Rev. 1.1	Delete I <sub>CC1</sub> Spec.	Sep.21.2004
Rev. 1.2	Added I Grade Spec. Revised <b>TEST CONDITION</b> of I <sub>CC</sub> /I <sub>SB1</sub> /I <sub>DR</sub> Revised V <sub>TERM</sub> to V <sub>T1</sub> and V <sub>T2</sub> Revised <b>FEATURES &amp; ORDERING INFORMATION</b> <b>Lead free and green package available</b> to <b>Green package available</b>	Apr.20.2009
Rev. 1.3	Deleted T <sub>SOLDER</sub> in <b>ABSOLUTE MAXIMUM RATINGS</b> Added packing type in <b>ORDERING INFORMATION</b> Adding PKG type : 32 TSOP II	Jan.05.2010
Rev. 1.4	Revised <b>PACKAGE OUTLINE DIMENSION</b> in page 8	May.07.2010
Rev. 1.5	Revised <b>PACKAGE OUTLINE DIMENSION</b> in page 8	Aug.30.2010
Rev. 1.6	Revised <b>ORDERING INFORMATION</b> in page 10 Deleted -8/15ns Spec. Deleted Power Type in <b>ORDERING INFORMATION</b> Deleted <b>WRITE CYCLE</b> Notes :	Jan.18.2017
Rev. 1.7	1. WE#,CE# must be high during all address transitions. In page 6 Deleted PKG type : 32 TSOP II	Oct.08.2019

### FEATURES

- Fast access time : 10/12ns
- Low power consumption:  
Operating current : 75/70mA (TYP.)  
Standby current : 0.6mA (TYP.)
- Single 3.3V power supply
- All inputs and outputs TTL compatible
- Fully static operation
- Tri-state output
- Data retention voltage : 2.0V (MIN.)
- **Green package available**
- Package : 32-pin 8mm x 13.4mm sTSP

### GENERAL DESCRIPTION

The LY61L1288 is a 1,048,576-bit high speed CMOS static random access memory organized as 131,072 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

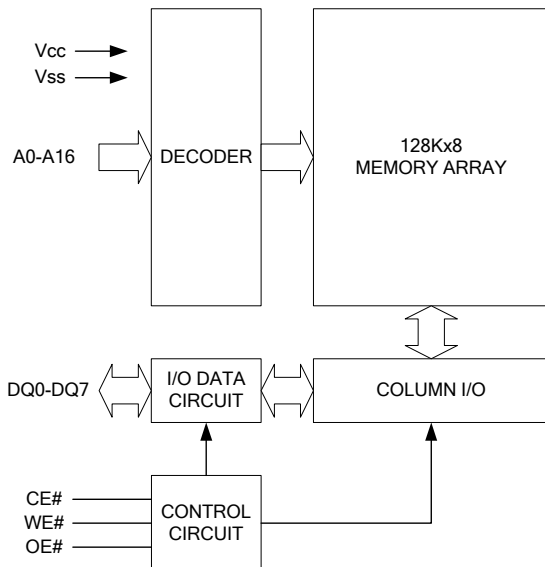
The LY61L1288 is well designed for high speed system application. Easy expansion is provided by using an active LOW Chip Enable(CE#). The active LOW Write Enable(WE#) controls both writing and reading of the memory.

The LY61L1288 operates from a single power supply of 3.3V and all inputs and outputs are fully TTL compatible

### PRODUCT FAMILY

Product Family	Operating Temperature	V <sub>CC</sub> Range	Speed	Power Dissipation	
				Standby(I <sub>SB1</sub> , TYP.)	Operating(I <sub>CC</sub> , TYP.)
LY61L1288	0 ~ 70°C	3.15 ~ 3.6V	10ns	0.6mA	75mA
LY61L1288	0 ~ 70°C	3.0 ~ 3.6V	12ns	0.6mA	70mA
LY61L1288(E)	-20 ~ 80°C	3.15 ~ 3.6V	10ns	0.6mA	75mA
LY61L1288(E)	-20 ~ 80°C	3.0 ~ 3.6V	12ns	0.6mA	70mA
LY61L1288(I)	-40 ~ 85°C	3.15 ~ 3.6V	10ns	0.6mA	75mA
LY61L1288(I)	-40 ~ 85°C	3.0 ~ 3.6V	12ns	0.6mA	70mA

### FUNCTIONAL BLOCK DIAGRAM



### PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A16	Address Inputs
DQ0 - DQ7	Data Inputs/Outputs
CE#	Chip Enable Input
WE#	Write Enable Input
OE#	Output Enable Input
V <sub>CC</sub>	Power Supply
V <sub>SS</sub>	Ground



#### PIN CONFIGURATION



sTSSOP



### ABSOLUTE MAXIMUM RATINGS\*

PARAMETER	SYMBOL	RATING	UNIT
Voltage on V <sub>CC</sub> relative to V <sub>SS</sub>	V <sub>T1</sub>	-0.5 to 4.6	V
Voltage on any other pin relative to V <sub>SS</sub>	V <sub>T2</sub>	-0.5 to V <sub>CC</sub> +0.5	V
Operating Temperature	T <sub>A</sub>	0 to 70(C grade)	°C
		-20 to 80(E grade)	
		-40 to 85(I grade)	
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C
Power Dissipation	P <sub>D</sub>	1	W
DC Output Current	I <sub>OUT</sub>	50	mA

\*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

### TRUTH TABLE

MODE	CE#	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	H	X	X	High-Z	I <sub>SB</sub> , I <sub>SB1</sub>
Output Disable	L	H	H	High-Z	I <sub>CC</sub>
Read	L	L	H	D <sub>OUT</sub>	I <sub>CC</sub>
Write	L	X	L	D <sub>IN</sub>	I <sub>CC</sub>

Note: H = V<sub>IH</sub>, L = V<sub>IL</sub>, X = Don't care.

### DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. <sup>*4</sup>	MAX.	UNIT	
Supply Voltage	V <sub>CC</sub>		-10	3.15	3.3	3.6	V
			-12	3.0	3.3	3.6	V
Input High Voltage	V <sub>IH</sub> <sup>*1</sup>		2.0	-	V <sub>CC</sub> +0.5	V	
Input Low Voltage	V <sub>IL</sub> <sup>*2</sup>		-0.3	-	0.8	V	
Input Leakage Current	I <sub>LI</sub>	V <sub>CC</sub> ≥ V <sub>IN</sub> ≥ V <sub>SS</sub>	-1	-	1	μA	
Output Leakage Current	I <sub>LO</sub>	V <sub>CC</sub> ≥ V <sub>OUT</sub> ≥ V <sub>SS</sub> , Output Disabled	-1	-	1	μA	
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -4mA	2.4	-	-	V	
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 8mA	-	-	0.4	V	
Average Operating Power supply Current	I <sub>CC</sub>	Cycle time = MIN. CE# = V <sub>IL</sub> , I <sub>I/O</sub> = 0mA Other pins at V <sub>IH</sub> or V <sub>IL</sub>	-10	-	75	120	mA
			-12	-	70	100	mA
Standby Power Supply Current	I <sub>SB</sub>	CE# = V <sub>IH</sub> , others at V <sub>IH</sub> or V <sub>IL</sub>	-	3	10	mA	
	I <sub>SB1</sub>	CE# ≥ V <sub>CC</sub> - 0.2V, Other pins at 0.2V or V <sub>CC</sub> -0.2V	-	0.6	3 <sup>*5</sup>	mA	

Notes:

- V<sub>IH</sub>(max) = V<sub>CC</sub> + 3.0V for pulse width less than 10ns.
- V<sub>IL</sub>(min) = V<sub>SS</sub> - 3.0V for pulse width less than 10ns.
- Over/Undershoot specifications are characterized, not 100% tested.
- Typical values are included for reference only and are not guaranteed or tested.  
Typical values are measured at V<sub>CC</sub> = V<sub>CC</sub>(TYP.) and T<sub>A</sub> = 25°C
- 1mA for special request

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**CAPACITANCE ( $T_A = 25^\circ\text{C}$ ,  $f = 1.0\text{MHz}$ )**

PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Input Capacitance	$C_{IN}$	-	6	pF
Input/Output Capacitance	$C_{I/O}$	-	8	pF

Note : These parameters are guaranteed by device characterization, but not production tested.

**AC TEST CONDITIONS**

Input Pulse Levels	0.2V to $V_{CC} - 0.2V$
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	$C_L = 30\text{pF} + 1\text{TTL}$ , $I_{OH}/I_{OL} = -4\text{mA}/8\text{mA}$

**AC ELECTRICAL CHARACTERISTICS****(1) READ CYCLE**

PARAMETER	SYM.	LY61L1288-10		LY61L1288-12		UNIT
		MIN.	MAX.	MIN.	MAX.	
Read Cycle Time	$t_{RC}$	10	-	12	-	ns
Address Access Time	$t_{AA}$	-	10	-	12	ns
Chip Enable Access Time	$t_{ACE}$	-	10	-	12	ns
Output Enable Access Time	$t_{OE}$	-	5	-	6	ns
Chip Enable to Output in Low-Z	$t_{CLZ}^*$	2	-	3	-	ns
Output Enable to Output in Low-Z	$t_{OLZ}^*$	0	-	0	-	ns
Chip Disable to Output in High-Z	$t_{CHZ}^*$	-	5	-	6	ns
Output Disable to Output in High-Z	$t_{OHZ}^*$	-	5	-	6	ns
Output Hold from Address Change	$t_{OH}$	3	-	3	-	ns

**(2) WRITE CYCLE**

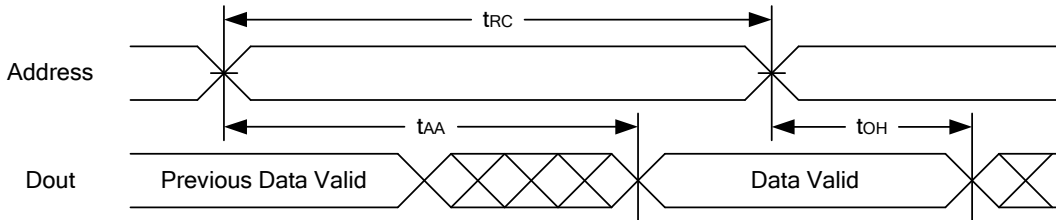
PARAMETER	SYM.	LY61L1288-10		LY61L1288-12		UNIT
		MIN.	MAX.	MIN.	MAX.	
Write Cycle Time	$t_{WC}$	10	-	12	-	ns
Address Valid to End of Write	$t_{AW}$	8	-	10	-	ns
Chip Enable to End of Write	$t_{CW}$	8	-	10	-	ns
Address Set-up Time	$t_{AS}$	0	-	0	-	ns
Write Pulse Width	$t_{WP}$	8	-	9	-	ns
Write Recovery Time	$t_{WR}$	0	-	0	-	ns
Data to Write Time Overlap	$t_{DW}$	6	-	7	-	ns
Data Hold from End of Write Time	$t_{DH}$	0	-	0	-	ns
Output Active from End of Write	$t_{OW}^*$	2	-	3	-	ns
Write to Output in High-Z	$t_{WHZ}^*$	-	6	-	7	ns

\*These parameters are guaranteed by device characterization, but not production tested.

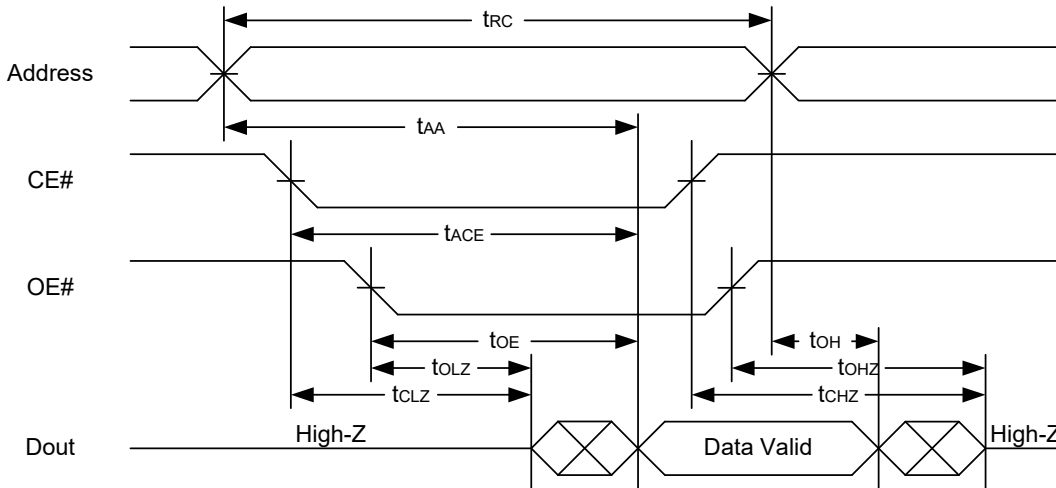


### TIMING WAVEFORMS

#### READ CYCLE 1 (Address Controlled) (1,2)



#### READ CYCLE 2 (CE# and OE# Controlled) (1,3,4,5)

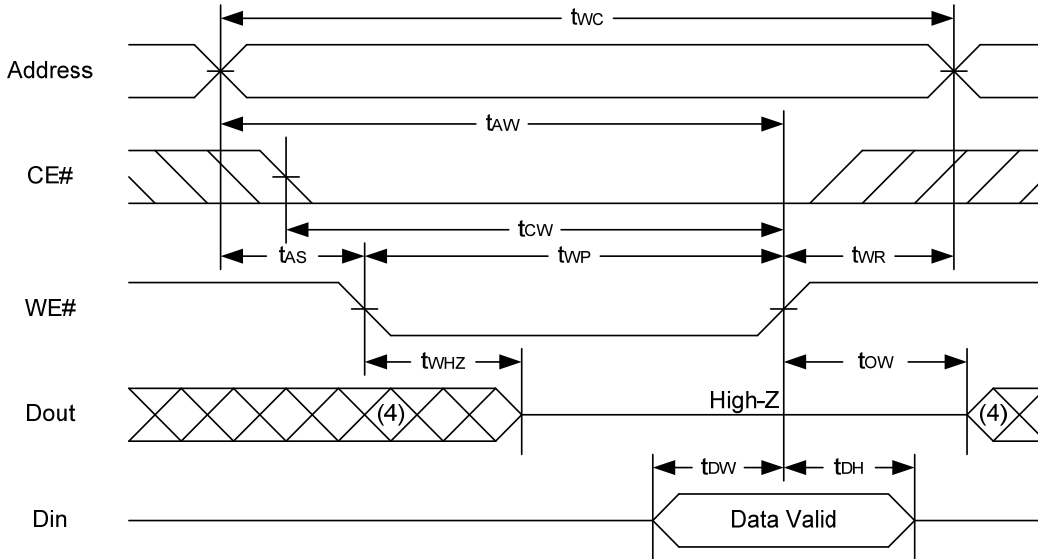


#### Notes :

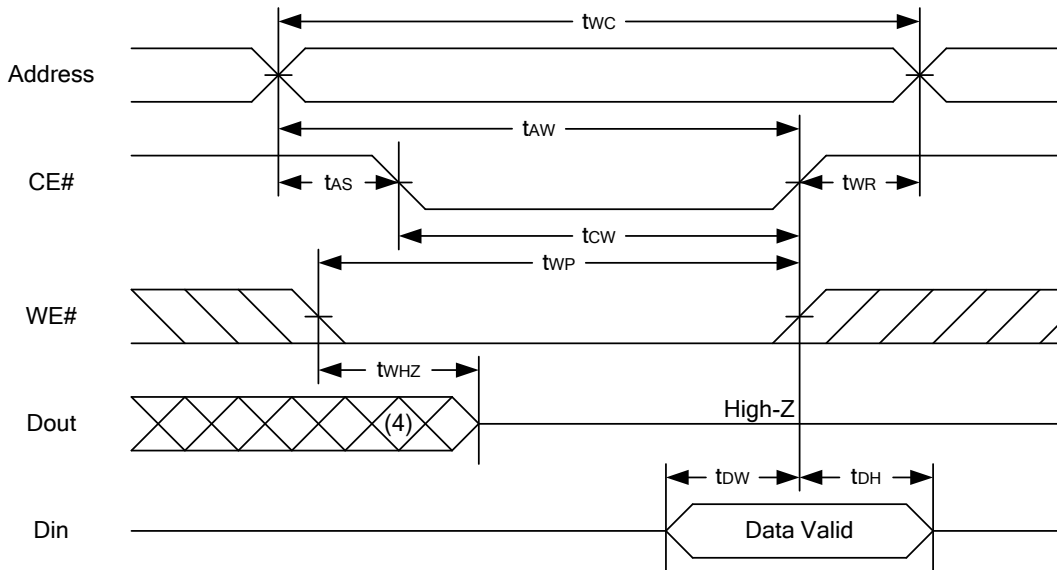
1. WE# is high for read cycle.
2. Device is continuously selected OE# = low, CE# = low.
3. Address must be valid prior to or coincident with CE# = low; otherwise  $t_{AA}$  is the limiting parameter.
4.  $t_{CLZ}$ ,  $t_{OLZ}$ ,  $t_{CHZ}$  and  $t_{OHZ}$  are specified with  $C_L = 5pF$ . Transition is measured  $\pm 500mV$  from steady state.
5. At any given temperature and voltage condition,  $t_{CHZ}$  is less than  $t_{CLZ}$ ,  $t_{OHZ}$  is less than  $t_{OLZ}$ .



#### WRITE CYCLE 1 (WE# Controlled) (1,2,4,5)



#### WRITE CYCLE 2 (CE# Controlled) (1,4,5)



#### Notes :

1. A write occurs during the overlap of a low CE#, low WE#.
2. During a WE# controlled write cycle with OE# low,  $t_{WP}$  must be greater than  $t_{WHZ} + t_{DW}$  to allow the drivers to turn off and data to be placed on the bus.
3. During this period, I/O pins are in the output state, and input signals must not be applied.
4. If the CE# low transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
5.  $t_{OW}$  and  $t_{WHZ}$  are specified with  $C_L = 5pF$ . Transition is measured  $\pm 500mV$  from steady state.

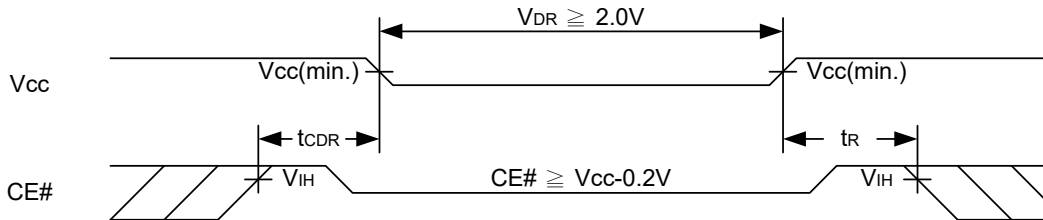


#### DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
V <sub>CC</sub> for Data Retention	V <sub>DR</sub>	CE# ≥ V <sub>CC</sub> - 0.2V	2.0	-	3.6	V
Data Retention Current	I <sub>DR</sub>	V <sub>CC</sub> = 2.0V, CE# ≥ V <sub>CC</sub> - 0.2V Others at 0.2V or V <sub>CC</sub> - 0.2V	-	0.4	2	mA
Chip Disable to Data Retention Time	t <sub>CDR</sub>	See Data Retention Waveforms (below)	0	-	-	ns
Recovery Time	t <sub>R</sub>		t <sub>RC</sub> *	-	-	ns

t<sub>RC</sub>\* = Read Cycle Time

#### DATA RETENTION WAVEFORM

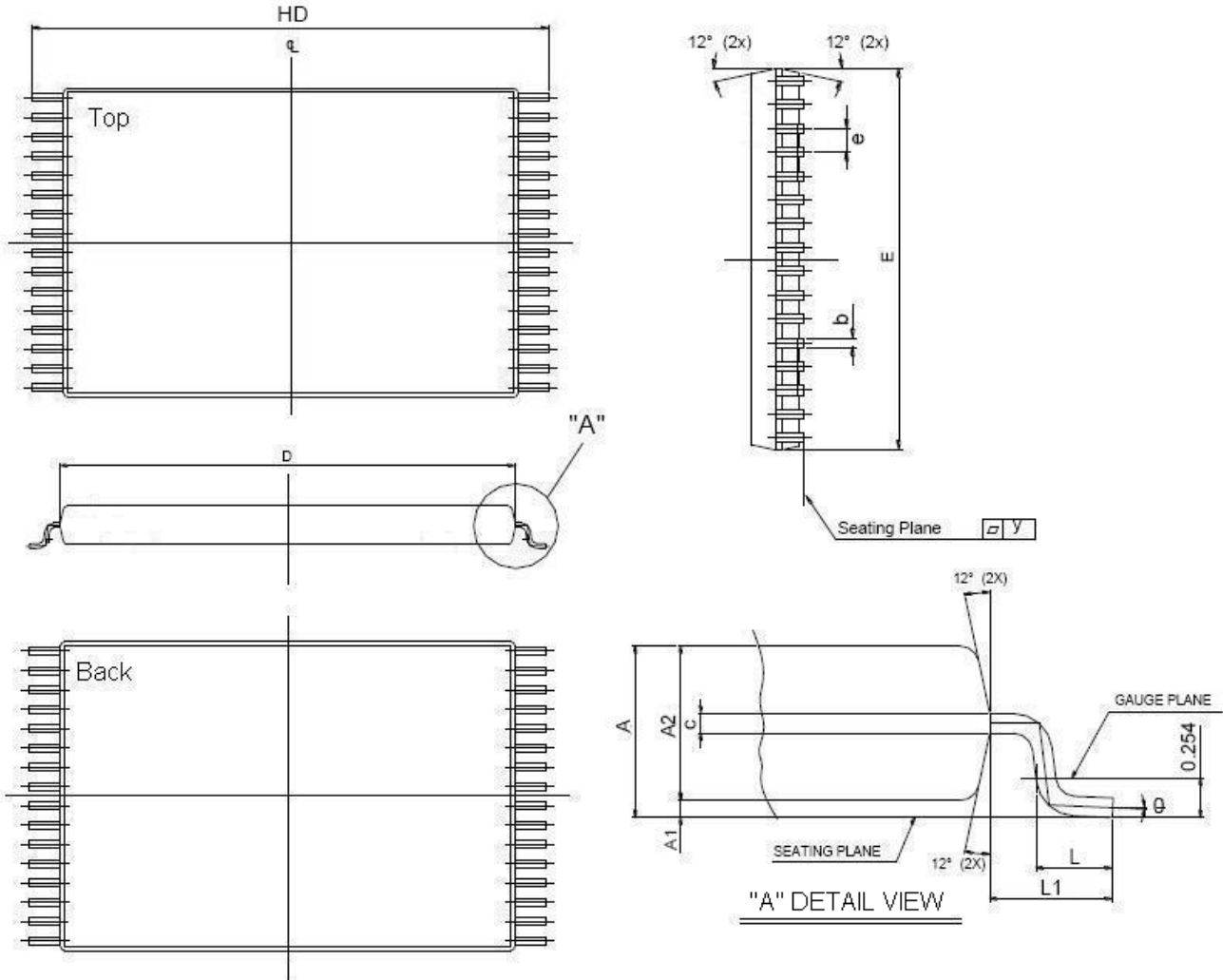






**PACKAGE OUTLINE DIMENSION**

**32-pin 8mm x 13.4mm sTSSOP Package Outline Dimension**



SYM.	UNIT	
	INCH(BASE)	MM(REF)
A	0.049 (MAX)	1.25 (MAX)
A1	0.004 ±0.002	0.10 ±0.05
A2	0.039 ±0.002	1.00 ±0.05
b	0.009 ±0.002	0.22 ±0.05
c	0.006 ±0.002	0.155 ±0.055
D	0.465 ±0.008	11.80 ±0.20
E	0.315 ±0.008	8.00 ±0.20
e	0.020 (TYP)	0.50 (TYP)
HD	0.528±0.008	13.40 ±0.20.
L	0.02 ±0.008	0.50 ±0.20
L1	0.031 ±0.005	0.8 ±0.125
y	0.003 (MAX)	0.076 (MAX)
θ	0°~5°	0°~5°



#### ORDERING INFORMATION

Package Type	Access Time (Speed)(ns)	Temperature Range(°C)	Packing Type	Lyontek Item No.
32-pin (8mm x 13.4mm) sTSOP	10	0°C~70°C	Tray	LY61L1288RL-10
			Tape Reel	LY61L1288RL-10T
		-20°C~80°C	Tray	LY61L1288RL-10E
			Tape Reel	LY61L1288RL-10ET
		-40°C~85°C	Tray	LY61L1288RL-10I
			Tape Reel	LY61L1288RL-10IT
	12	0°C~70°C	Tray	LY61L1288RL-12
			Tape Reel	LY61L1288RL-12T
		-20°C~80°C	Tray	LY61L1288RL-12E
			Tape Reel	LY61L1288RL-12ET
		-40°C~85°C	Tray	LY61L1288RL-12I
			Tape Reel	LY61L1288RL-12IT



**Lyontek Inc.**

**LY61L1288**

Rev. 1.7

**128K X 8 BIT HIGH SPEED CMOS SRAM**

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